

# 2.5V Drive Nch + Nch MOSFET

## EM6K31

### ● Structure

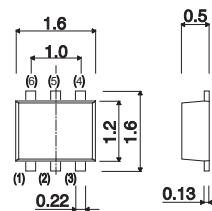
Silicon N-channel MOSFET

### ● Features

- 1) High speed switching.
- 2) Small package(EMT6).
- 3) Low voltage drive(2.5V drive).

### ● Dimensions (Unit : mm)

EMT6



Abbreviated symbol : K31

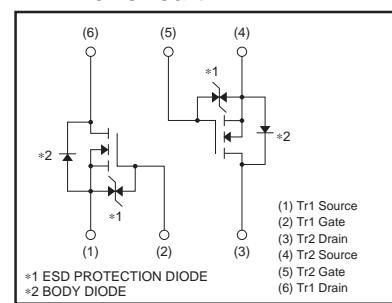
### ● Application

Switching

### ● Packaging specifications

Type	Package	Taping
	Code	T2R
	Basic ordering unit (pieces)	8000
EM6K31		○

### ● Inner circuit



### ● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V <sub>DSS</sub>	60	V
Gate-source voltage		V <sub>GSS</sub>	±20	V
Drain current	Continuous	I <sub>D</sub>	±250	mA
	Pulsed	I <sub>DP</sub>	*1 ±1	A
Source current (Body Diode)	Continuous	I <sub>S</sub>	125	mA
	Pulsed	I <sub>SP</sub>	*1 1	A
Power dissipation		P <sub>D</sub>	150 120	mW / TOTAL mW / ELEMENT
Channel temperature		T <sub>ch</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to +150	°C

\*1 Pw≤10μs, Duty cycle≤1%

\*2 Each terminal mounted on a recommended land.

### ● Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	R <sub>th</sub> (ch-a) <sup>*</sup>	833	°C / W /TOTAL
		1042	°C / W /ELEMENT

\* Each terminal mounted on a recommended land.

## ● Electrical characteristics (Ta = 25°C)

&lt;It is the same ratings for Tr1 and Tr2.&gt;

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	-	-	$\pm 10$	$\mu A$	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	60	-	-	V	$I_D=1mA, V_{GS}=0V$
Zero gate voltage drain current	$I_{DSS}$	-	-	1	$\mu A$	$V_{DS}=60V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(\text{th})}$	1.0	-	2.3	V	$V_{DS}=10V, I_D=1mA$
Static drain-source on-state resistance	$R_{DS(\text{on})}^*$	-	1.7	2.4	$\Omega$	$I_D=250mA, V_{GS}=10V$
		-	2.1	3.0		$I_D=250mA, V_{GS}=4.5V$
		-	2.3	3.2		$I_D=250mA, V_{GS}=4.0V$
		-	3.0	12.0		$I_D=10mA, V_{GS}=2.5V$
Forward transfer admittance	$ Y_{fs} ^*$	0.25	-	-	S	$I_D=250mA, V_{DS}=10V$
Input capacitance	$C_{iss}$	-	15	-	pF	$V_{DS}=25V$
Output capacitance	$C_{oss}$	-	4.5	-	pF	$V_{GS}=0V$
Reverse transfer capacitance	$C_{rss}$	-	2.0	-	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	3.5	-	ns	$I_D=100mA, V_{DD}=30V$
Rise time	$t_r^*$	-	5	-	ns	$V_{GS}=10V$
Turn-off delay time	$t_{d(off)}^*$	-	18	-	ns	$R_L=300\Omega$
Fall time	$t_f^*$	-	28	-	ns	$R_G=10\Omega$

\*Pulsed

## ● Body diode characteristics (Source-Drain) (Ta = 25°C)

&lt;It is the same ratings for Tr1 and Tr2.&gt;

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	$V_{SD}^*$	-	-	1.2	V	$I_s=250mA, V_{GS}=0V$

\*Pulsed

●Electrical characteristic curves

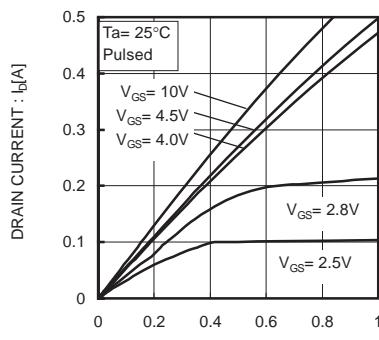
DRAIN-SOURCE VOLTAGE :  $V_{DS}$ [V]

Fig.1 Typical Output Characteristics( I )

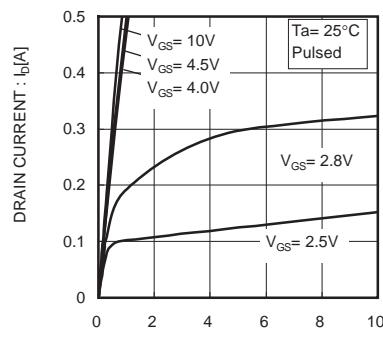
DRAIN-SOURCE VOLTAGE :  $V_{DS}$ [V]

Fig.2 Typical Output Characteristics( II )

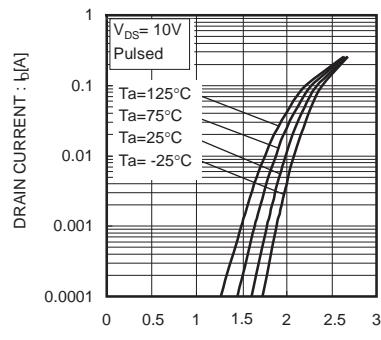
GATE-SOURCE VOLTAGE :  $V_{GS}$ [V]

Fig.3 Typical Transfer Characteristics

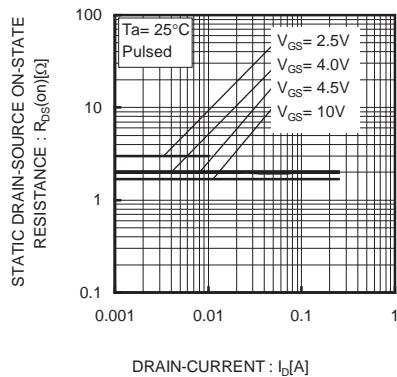
DRAIN-CURRENT :  $I_D$ [A]

Fig.4 Static Drain-Source On-State Resistance vs. Drain Current( I )

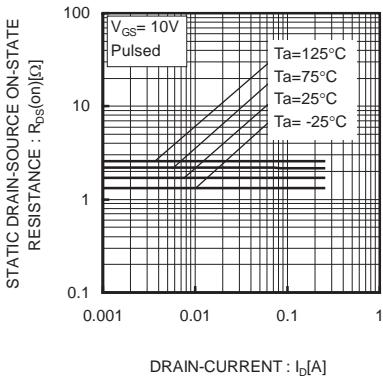
DRAIN-CURRENT :  $I_D$ [A]

Fig.5 Static Drain-Source On-State Resistance vs. Drain Current( II )

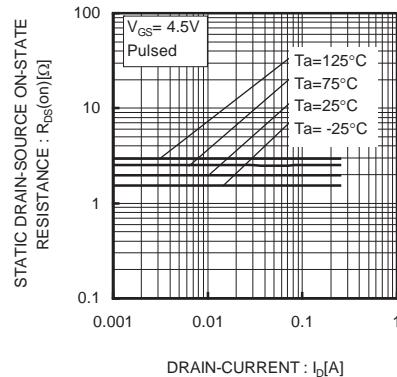
DRAIN-CURRENT :  $I_D$ [A]

Fig.6 Static Drain-Source On-State Resistance vs. Drain Current( III )

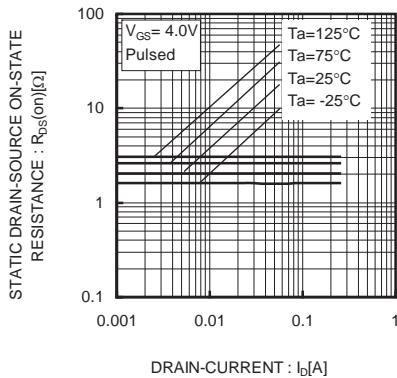
DRAIN-CURRENT :  $I_D$ [A]

Fig.7 Static Drain-Source On-State Resistance vs. Drain Current( IV )

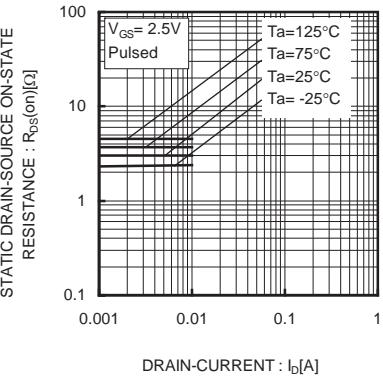
DRAIN-CURRENT :  $I_D$ [A]

Fig.8 Static Drain-Source On-State Resistance vs. Drain Current( IV )

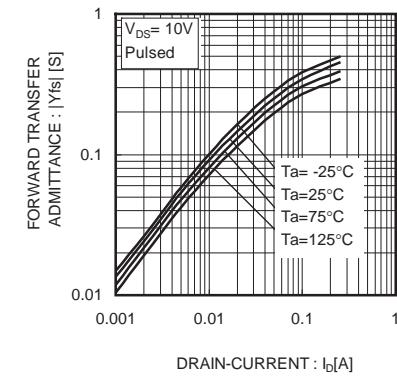
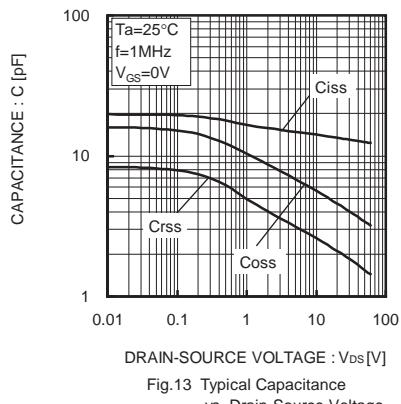
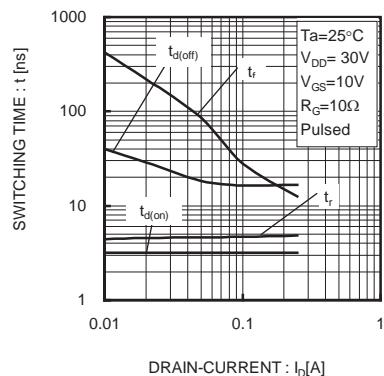
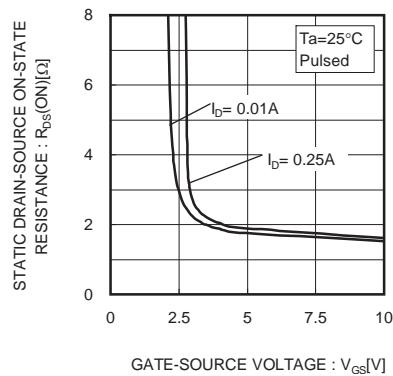
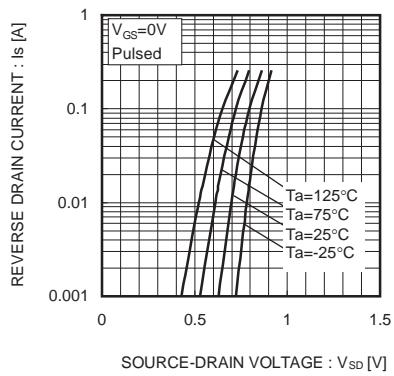
DRAIN-CURRENT :  $I_D$ [A]

Fig.9 Forward Transfer Admittance vs. Drain Current



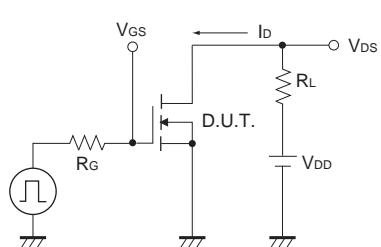
**●Measurement circuits**

Fig.1-1 Switching time measurement circuit

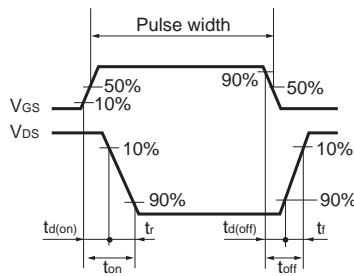


Fig.1-2 Switching waveforms

**●Notice**

This product might cause chip aging and breakdown under the large electrified environment.  
Please consider to design ESD protection circuit.

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